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- Output Voltage Translation Tracks V<sub>CC</sub>
- Supports Mixed-Mode Signal Operation On All Data I/O Ports
  - 5-V Input Down To 3.3-V Output Level Shift With 3.3-V V<sub>CC</sub>
  - 5-V/3.3-V Input Down To 2.5-V Output Level Shift With 2.5-V V<sub>CC</sub>
- 5-V-Tolerant I/Os With Device Powered Up or Powered Down
- Bidirectional Data Flow, With Near-Zero Propagation Delay
- Low ON-State Resistance (r<sub>on</sub>) Characteristics (r<sub>on</sub> = 5 Ω Typical)
- Low Input/Output Capacitance Minimizes Loading (Cio(OFF) = 8 pF Typical)
- Data and Control Inputs Provide Undershoot Clamp Diodes
- Low Power Consumption (I<sub>CC</sub> = 20 μA Max)

- V<sub>CC</sub> Operating Range From 2.3 V to 3.6 V
- Data I/Os Support 0- to 5-V Signaling Levels (0.8 V, 1.2 V, 1.5 V, 1.8 V, 2.5 V, 3.3 V, 5 V)
- Control Inputs Can Be Driven by TTL or 5-V/3.3-V CMOS Outputs
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Performance Tested Per JESD 22

   2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)
- Supports Digital Applications: Level Translation, Memory Interleaving, Bus Isolation
- Ideal for Low-Power Portable Equipment

DBQ, DGV, DW, OR PW PACKAGE (TOP VIEW)

|     | _            |                 |                   |
|-----|--------------|-----------------|-------------------|
| BE  | [1           | U <sub>24</sub> | ] v <sub>cc</sub> |
| 1B1 | 2            | 23              | 5B2               |
| 1A1 | <b>[</b> ] 3 | 22              | 5A2               |
| 1A2 | 4            | 21              | 5A1               |
| 1B2 | 5            | 20              | 5B1               |
| 2B1 | 6            | 19              | <b>4</b> B2       |
| 2A1 | <b>[</b> 7   | 18              | 4A2               |
| 2A2 | 8            | 17              | 4A1               |
| 2B2 | 9            | 16              | <b>4</b> B1       |
| 3B1 | 10           | 15              | 3B2               |
| 3A1 | 11           | 14              | 3A2               |
| GND | 12           | 13              | ] вх              |

# description/ordering information

#### **ORDERING INFORMATION**

| TA            | PACKAGE           | <u>=</u> †    | ORDERABLE<br>PART NUMBER | TOP-SIDE<br>MARKING |
|---------------|-------------------|---------------|--------------------------|---------------------|
|               | 0010 014          | Tube          | SN74CB3T3383DW           | ODOTOOOO            |
|               | SOIC – DW         | Tape and reel | SN74CB3T3383DWR          | CB3T3383            |
| -40°C to 85°C | SSOP (QSOP) – DBQ | Tape and reel | SN74CB3T3383DBQR         | CB3T3383            |
| -40 C 10 85 C | TOCOD DW          | Tube          | SN74CB3T3383PW           | K0202               |
|               | TSSOP – PW        | Tape and reel | SN74CB3T3383PWR          | KS383               |
|               | TVSOP – DGV       | Tape and reel | SN74CB3T3383DGVR         | KS383               |

<sup>†</sup> Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

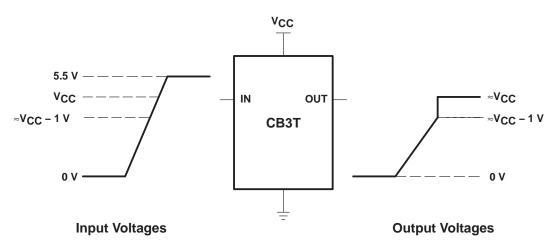


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#### description/ordering information (continued)

The SN74CB3T3383 is a high-speed TTL-compatible FET bus-exchange switch with low ON-state resistance (ron), allowing for minimal propagation delay. The device fully supports mixed-mode signal operation on all data I/O ports by providing voltage translation that tracks V<sub>CC</sub>. The SN74CB3T3383 supports systems using 5-V TTL, 3.3-V LVTTL, and 2.5-V CMOS switching standards, as well as user-defined switching levels (see Figure 1).



NOTE A: If the input high voltage (VIH) level is greater than or equal to V<sub>CC</sub> - 1 V, and less than or equal to 5.5 V, then the output high voltage (VOH) level will be equal to approximately the VCC voltage level.

#### Figure 1. Typical DC Voltage Translation Characteristics

The SN74CB3T3383 is organized as a 10-bit bus switch or as a 5-bit bus-exchange with enable (BE) input. When used as a 5-bit bus-exchange, the device provides data exchanging between four signal ports. When BE is low, the bus-exchange switch is ON, and the select input (BX) controls the data path. When BE is high, the bus-exchange switch is OFF, and a high-impedance state exists between the A and B ports.

This device is fully specified for partial-power-down applications using Ioff. The Ioff feature ensures that damaging current will not backflow through the device when it is powered down. The device has isolation during power off.

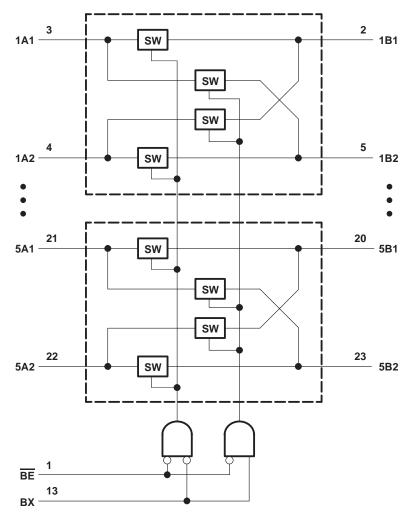
To ensure the high-impedance state during power up or power down, BE should be tied to V<sub>CC</sub> through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.



#### SN74CB3T3383 10-BIT FET BUS-EXCHANGE SWITCH 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER SCDS158A - OCTOBER 2003 - REVISED DECEMBER 2004

| ſ | INP | UTS |    |    |  |
|---|-----|-----|----|----|--|
| ĺ | BE  | вх  | A1 | A2 | FUNCTION                               |
|   | L   | L   | B1 | B2 | A1 port = B1 port<br>A2 port = B2 port |
|   | L   | Н   | B2 | B1 | A1 port = B2 port<br>A2 port = B1 port |
|   | Н   | Х   | Z  | Z  | Disconnect                             |

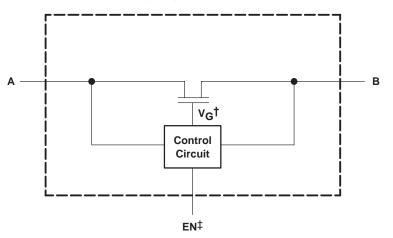
# logic diagram (positive logic)





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### simplified schematic, each FET switch (SW)



<sup>†</sup> Gate Voltage (V<sub>G</sub>) is approximately equal to V<sub>CC</sub> + V<sub>T</sub> when the switch is ON and V<sub>I</sub> > V<sub>CC</sub> + V<sub>T</sub>. <sup>‡</sup> EN is the internal enable signal applied to the switch.

#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)§

| Supply voltage range, V <sub>CC</sub> (see Note 1)                   | /  |
|--|----|
| Control input voltage range, VIN (see Notes 1 and 2)                 | /  |
| Switch I/O voltage range, V <sub>I/O</sub> (see Notes 1, 2, and 3)   | /  |
| Control input clamp current, I <sub>IK</sub> (V <sub>IN</sub> < 0)   | ١  |
| I/O port clamp current, I <sub>I/OK</sub> (V <sub>I/O</sub> < 0)     | ١  |
| ON-state switch current, II/O (see Note 4) ±128 mA                   | ٩. |
| Continuous current through V <sub>CC</sub> or GND terminals          | ٩. |
| Package thermal impedance, θ <sub>JA</sub> (see Note 5): DBQ package | Ι  |
| DGV package  | /  |
| DW package   | Ι  |
| PW package   | /  |
| Storage temperature range, T <sub>stg</sub>                          | )  |

§ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltages are with respect to ground unless otherwise specified.
  - 2. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
  - 3. VI and VO are used to denote specific conditions for  $V_{I/O}$ .
  - 4. I and I are used to denote specific conditions for  $I_{I/O}$ .
  - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 6)

|                  |  |                                    | MIN | MAX | UNIT |
|------------------|--|------------------------------------|-----|-----|------|
| VCC              | Supply voltage                           |                                    | 2.3 | 3.6 | V    |
|                  | LP-shi based a sector D-sector setter as | $V_{CC}$ = 2.3 V to 2.7 V          | 1.7 | 5.5 |      |
| VIH              | High-level control input voltage         | V <sub>CC</sub> = 2.7 V to 3.6 V   | 2   | 5.5 | V    |
|                  | Law law barden frankrikeren              | V <sub>CC</sub> = 2.3 V to 2.7 V   | 0   | 0.7 |      |
| VIL              | Low-level control input voltage          | $V_{CC} = 2.7 V \text{ to } 3.6 V$ | 0   | 0.8 | V    |
| V <sub>I/O</sub> | Data input/output voltage                |                                    | 0   | 5.5 | V    |
| TA               | Operating free-air temperature           |                                    | -40 | 85  | °C   |

NOTE 6: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PA                  | RAMETER                             | TEST CON   | DITIONS                                    | MIN | TYP† | MAX | UNIT |  |
|---------------------|-------------------------------------|--|--|-----|------|-----|------|--|
| VIK                 |                                     | $V_{CC} = 3 V,$<br>$I_{I} = -18 mA$  |  |     |      |     |      |  |
| VOH                 |                                     | See Figures 3 and 4  |  |     |      |     |      |  |
| I <sub>IN</sub> ‡   | Control inputs                      | $V_{CC} = 3.6 V,$<br>$V_{IN}^{\ddagger} = 3.6 V \text{ to } 5.5 V \text{ or GND}$  |  |     |      | ±10 | μΑ   |  |
|                     | -                                   | $V_{\rm CC} = 3.6  \text{V},$  | $V_{I} = V_{CC} - 0.7 V \text{ to } 5.5 V$ |     |      | ±20 |      |  |
| l <sub>i</sub>      |                                     | Switch ON,   | $V_{I}$ = 0.7 V to $V_{CC}$ – 0.7 V        |     |      | -40 | μΑ   |  |
|                     |                                     | $V_{IN} = V_{CC}$ or GND   | $V_{I} = 0$ to 0.7 V                       |     |      | ±5  |      |  |
| I <sub>OZ</sub> §   |                                     | $\label{eq:VCC} \begin{array}{l} V_{CC} = 3.6 \ \text{V}, \\ V_{O} = 0 \ \text{to} \ 5.5 \ \text{V}, \\ V_{I} = 0, \\ \text{Switch OFF}, \\ V_{IN} = V_{CC} \ \text{or GND} \end{array}$ |  |     |      | ±10 | μΑ   |  |
| l <sub>off</sub>    |                                     | $V_{CC} = 0,$<br>$V_{O} = 0$ to 5.5 V,<br>$V_{I} = 0,$   |  |     |      | 10  | μΑ   |  |
|                     | $V_{CC} = 3.6 V,$<br>$I_{I/O} = 0,$ |  | $V_I = V_{CC}$ or GND                      |     |      | 20  |      |  |
| ICC                 |                                     | Switch ON or OFF,<br>$V_{IN} = V_{CC}$ or GND  | VI = 5.5 V                                 | 20  |      | μΑ  |      |  |
| ∆ICC¶               | Control inputs                      | $V_{CC}$ = 3 V to 3.6 V,<br>One input at $V_{CC}$ – 0.6 V,<br>Other inputs at $V_{CC}$ or GND  |  |     |      | 300 | μΑ   |  |
| C <sub>in</sub>     | Control inputs                      | $V_{CC} = 3.3 V,$<br>$V_{IN} = V_{CC} \text{ or GND}$  |  |     | 4    |     | pF   |  |
| C <sub>io(OFF</sub> | )                                   | $V_{CC} = 3.3 \text{ V},$<br>$V_{I/O} = 5.5 \text{ V}, 3.3 \text{ V}, \text{ or GND},$<br>Switch OFF,<br>$V_{IN} = V_{CC} \text{ or GND}$  |  |     | 8    |     | pF   |  |
|                     | $V_{CC} = 3.3 V,$<br>Switch ON,     |  | V <sub>I/O</sub> = 5.5 V or 3.3 V          |     | 7    |     | pF   |  |
| C <sub>io(ON)</sub> |                                     | $V_{IN} = V_{CC}$ or GND   | V <sub>I/O</sub> = GND                     |     | 21   |     | P1   |  |
|                     |                                     | $V_{CC} = 2.3 V,$<br>TYP at $V_{CC} = 2.5 V,$  | I <sub>O</sub> = 24 mA                     |     | 5    | 9   |      |  |
| ron <sup>#</sup>    |                                     |  | I <sub>O</sub> = 16 mA                     | 5 9 |      | 9   | Ω    |  |
| 511                 |                                     | V <sub>CC</sub> = 3 V,   |  | 5   | 8    |     |      |  |
|                     |                                     | $V_{I} = 0$  | I <sub>O</sub> = 32 mA                     |     | 5    | 8   |      |  |

<sup>†</sup> All typical values are at V<sub>CC</sub> = 3.3 V (unless otherwise noted), T<sub>A</sub> = 25°C. <sup>‡</sup> V<sub>IN</sub> and I<sub>IN</sub> refer to control inputs. V<sub>I</sub>, V<sub>O</sub>, I<sub>I</sub>, and I<sub>O</sub> refer to data pins. § For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

This is the increase in supply current for each input that is at the specified TTL voltage level, rather than V<sub>CC</sub> or GND.

# Measured by the voltage drop between A and B terminals at the indicated current through the switch. ON-state resistance is determined by the lower of the voltages of the two (A or B) terminals.



### SN74CB3T3383 **10-BIT FET BUS-EXCHANGE SWITCH** 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER SCDS158A - OCTOBER 2003 - REVISED DECEMBER 2004

#### switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 2)

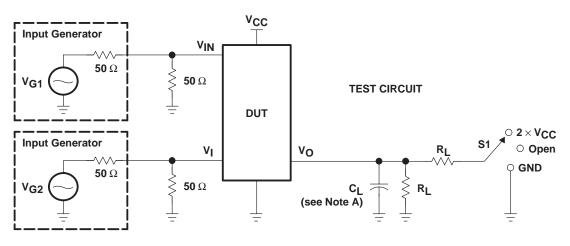
| PARAMETER          | FROM<br>(INPUT) | TO       | ۷ <sub>CC</sub> =<br>± 0.2 | 2.5 V<br>2 V | V <sub>CC</sub> =<br>± 0.3 | UNIT |    |
|--------------------|-----------------|----------|----------------------------|--------------|----------------------------|------|----|
|                    | (INPUT)         | (OUTPUT) | MIN                        | MAX          | MIN                        | MAX  |    |
| t <sub>pd</sub> †  | A or B          | B or A   |                            | 0.15         |                            | 0.25 |    |
| <sup>t</sup> pd(s) | BX              | A or B   | 1                          | 15           | 1                          | 10   | ns |
| <sup>t</sup> en    | BE              | A or B   | 1                          | 13.5         | 1                          | 9    | ns |
| <sup>t</sup> dis   | BE              | A or B   | 1                          | 7            | 1                          | 8.5  | ns |

<sup>†</sup> The propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).

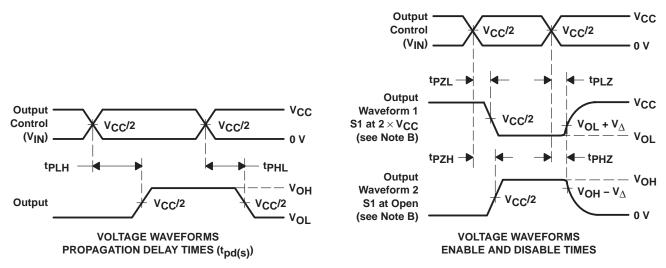


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#### PARAMETER MEASUREMENT INFORMATION



| TEST                               | VCC   | S1  | RL                           | VI                           | сL             | $v_\Delta$      |
|------------------------------------|---|---|------------------------------|------------------------------|----------------|-----------------|
| <sup>t</sup> pd(s)                 | $\begin{array}{c}\textbf{2.5 V}\pm\textbf{0.2 V}\\\textbf{3.3 V}\pm\textbf{0.3 V}\end{array}$         | Open<br>Open  | <b>500</b> Ω<br><b>500</b> Ω | 3.6 V or GND<br>5.5 V or GND | 30 pF<br>50 pF |                 |
| <sup>t</sup> PLZ <sup>/t</sup> PZL | $\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$ | $\begin{array}{c} 2 \times \mathbf{V_{CC}} \\ 2 \times \mathbf{V_{CC}} \end{array}$ | <b>500</b> Ω<br><b>500</b> Ω | GND<br>GND                   | 30 pF<br>50 pF | 0.15 V<br>0.3 V |
| tPHZ/tPZH                          | $\begin{array}{c} \textbf{2.5 V} \pm \textbf{0.2 V} \\ \textbf{3.3 V} \pm \textbf{0.3 V} \end{array}$ | Open<br>Open  | <b>500</b> Ω<br><b>500</b> Ω | 3.6 V<br>5.5 V               | 30 pF<br>50 pF | 0.15 V<br>0.3 V |

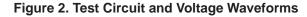


NOTES: A. CL includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.

C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>f</sub>  $\leq$  2.5 ns. t<sub>f</sub>  $\leq$  2.5 ns.

- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
- G. tpLH and tpHL are the same as tpd(s). The tpd propagation delay is the calculated RC time constant of the typical ON-state resistance of the switch and the specified load capacitance, when driven by an ideal voltage source (zero output impedance).
- H. All parameters and waveforms are not applicable to all devices.





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## **TYPICAL CHARACTERISTICS**

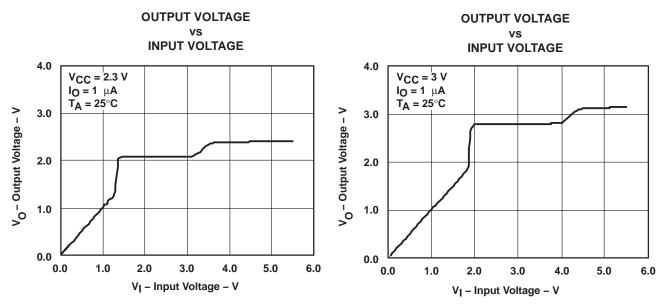


Figure 3. Data Output Voltage vs Data Input Voltage



#### SN74CB3T3383 10-BIT FET BUS-EXCHANGE SWITCH 2.5-V/3.3-V LOW-VOLTAGE BUS SWITCH WITH 5-V-TOLERANT LEVEL SHIFTER SCDS158A – OCTOBER 2003 – REVISED DECEMBER 2004

#### **OUTPUT VOLTAGE HIGH OUTPUT VOLTAGE HIGH** vs vs SUPPLY VOLTAGE SUPPLY VOLTAGE 4.0 4.0 V<sub>CC</sub> = 2.3 V to 3.6 V V<sub>CC</sub> = 2.3 V to 3.6 V V<sub>OH</sub> - Output Voltage High - V $V_{1} = 5.5 V$ V<sub>OH</sub> - Output Voltage High - V V<sub>I</sub> = 5.5 V **100 μA** T<sub>A</sub> = 85°C 3.5 T<sub>A</sub> = 25°C **100 µA** 3.5 8 mÅ 8 mÅ 16 mA 24 mA 16 mA 3.0 24 mA 3.0 2.5 2.5 2.0 2.0 1.5 1.5 2.3 2.5 2.7 2.9 3.1 3.3 3.5 3.7 2.3 2.5 2.7 2.9 3.1 3.3 3.5 3.7 V<sub>CC</sub> – Supply Voltage – V V<sub>CC</sub> – Supply Voltage – V

### **TYPICAL CHARACTERISTICS (continued)**



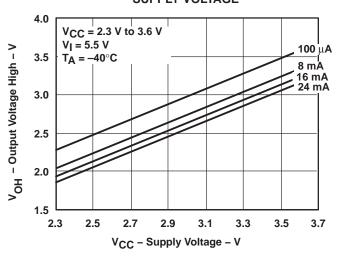


Figure 4. V<sub>OH</sub> Values





24-Jan-2013

## PACKAGING INFORMATION

| Orderable Device  | Status<br>(1) | Package Type | Package<br>Drawing | Pins | Package Qty | Eco Plan<br>(2)            | Lead/Ball Finish | MSL Peak Temp       | Op Temp (°C) | Top-Side Markings | Samples |
|-------------------|---------------|--------------|--------------------|------|-------------|----------------------------|------------------|---------------------|--------------|-------------------|---------|
| 74CB3T3383DBQRE4  | ACTIVE        | SSOP         | DBQ                | 24   | 2500        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 85    | CB3T3383          | Samples |
| 74CB3T3383DBQRG4  | ACTIVE        | SSOP         | DBQ                | 24   | 2500        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 85    | CB3T3383          | Samples |
| 74CB3T3383DGVRE4  | ACTIVE        | TVSOP        | DGV                | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |
| 74CB3T3383DGVRG4  | ACTIVE        | TVSOP        | DGV                | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |
| SN74CB3T3383DBQR  | ACTIVE        | SSOP         | DBQ                | 24   | 2500        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-2-260C-1 YEAR | -40 to 85    | CB3T3383          | Samples |
| SN74CB3T3383DGVR  | ACTIVE        | TVSOP        | DGV                | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |
| SN74CB3T3383DW    | ACTIVE        | SOIC         | DW                 | 24   | 25          | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | CB3T3383          | Samples |
| SN74CB3T3383DWE4  | ACTIVE        | SOIC         | DW                 | 24   | 25          | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | CB3T3383          | Samples |
| SN74CB3T3383DWG4  | ACTIVE        | SOIC         | DW                 | 24   | 25          | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | CB3T3383          | Samples |
| SN74CB3T3383DWR   | ACTIVE        | SOIC         | DW                 | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | CB3T3383          | Samples |
| SN74CB3T3383DWRE4 | ACTIVE        | SOIC         | DW                 | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | CB3T3383          | Samples |
| SN74CB3T3383DWRG4 | ACTIVE        | SOIC         | DW                 | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | CB3T3383          | Samples |
| SN74CB3T3383PW    | ACTIVE        | TSSOP        | PW                 | 24   | 60          | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |
| SN74CB3T3383PWE4  | ACTIVE        | TSSOP        | PW                 | 24   | 60          | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |
| SN74CB3T3383PWG4  | ACTIVE        | TSSOP        | PW                 | 24   | 60          | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |
| SN74CB3T3383PWR   | ACTIVE        | TSSOP        | PW                 | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |
| SN74CB3T3383PWRE4 | ACTIVE        | TSSOP        | PW                 | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM  | -40 to 85    | KS383             | Samples |



24-Jan-2013

| Orderable Device  | Status | Package Type | •       | Pins | Package Qty | Eco Plan                   | Lead/Ball Finish | MSL Peak Temp      | Op Temp (°C) | Top-Side Markings | Samples |
|-------------------|--------|--------------|---------|------|-------------|----------------------------|------------------|--------------------|--------------|-------------------|---------|
|                   | (1)    |              | Drawing |      |             | (2)                        |                  | (3)                |              | (4)               |         |
| SN74CB3T3383PWRG4 | ACTIVE | TSSOP        | PW      | 24   | 2000        | Green (RoHS<br>& no Sb/Br) | CU NIPDAU        | Level-1-260C-UNLIM | -40 to 85    | KS383             | Samples |

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

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# PACKAGE MATERIALS INFORMATION

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## TAPE AND REEL INFORMATION





# QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



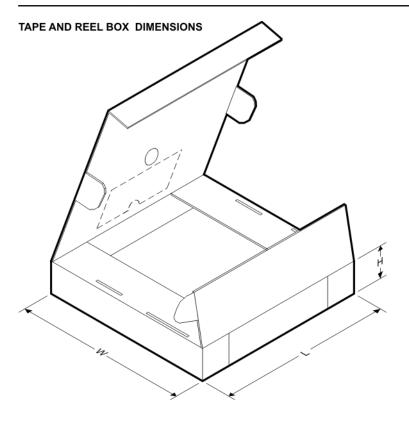
| *All dimensions are nominal<br>Device | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|---------------------------------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| SN74CB3T3383DBQR                      | SSOP            | DBQ                | 24 | 2500 | 330.0                    | 16.4                     | 6.5        | 9.0        | 2.1        | 8.0        | 16.0      | Q1               |
| SN74CB3T3383DGVR                      | TVSOP           | DGV                | 24 | 2000 | 330.0                    | 12.4                     | 6.9        | 5.6        | 1.6        | 8.0        | 12.0      | Q1               |
| SN74CB3T3383DWR                       | SOIC            | DW                 | 24 | 2000 | 330.0                    | 24.4                     | 10.75      | 15.7       | 2.7        | 12.0       | 24.0      | Q1               |
| SN74CB3T3383PWR                       | TSSOP           | PW                 | 24 | 2000 | 330.0                    | 16.4                     | 6.95       | 8.3        | 1.6        | 8.0        | 16.0      | Q1               |

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# PACKAGE MATERIALS INFORMATION

26-Jan-2013



\*All dimensions are nominal

| Device           | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| SN74CB3T3383DBQR | SSOP         | DBQ             | 24   | 2500 | 367.0       | 367.0      | 38.0        |
| SN74CB3T3383DGVR | TVSOP        | DGV             | 24   | 2000 | 367.0       | 367.0      | 35.0        |
| SN74CB3T3383DWR  | SOIC         | DW              | 24   | 2000 | 367.0       | 367.0      | 45.0        |
| SN74CB3T3383PWR  | TSSOP        | PW              | 24   | 2000 | 367.0       | 367.0      | 38.0        |

# **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).

D. Falls within JEDEC MS-013 variation AD.



DBQ (R-PDSO-G24)

PLASTIC SMALL-OUTLINE PACKAGE



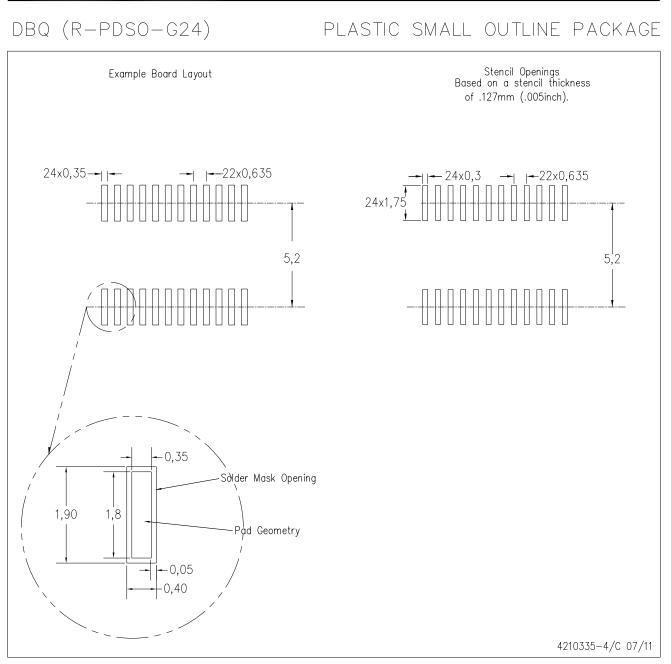
NOTES: A. All linear dimensions are in inches (millimeters).

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15) per side.

D. Falls within JEDEC MO-137 variation AE.





NOTES:

- A. All linear dimensions are in millimeters.B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

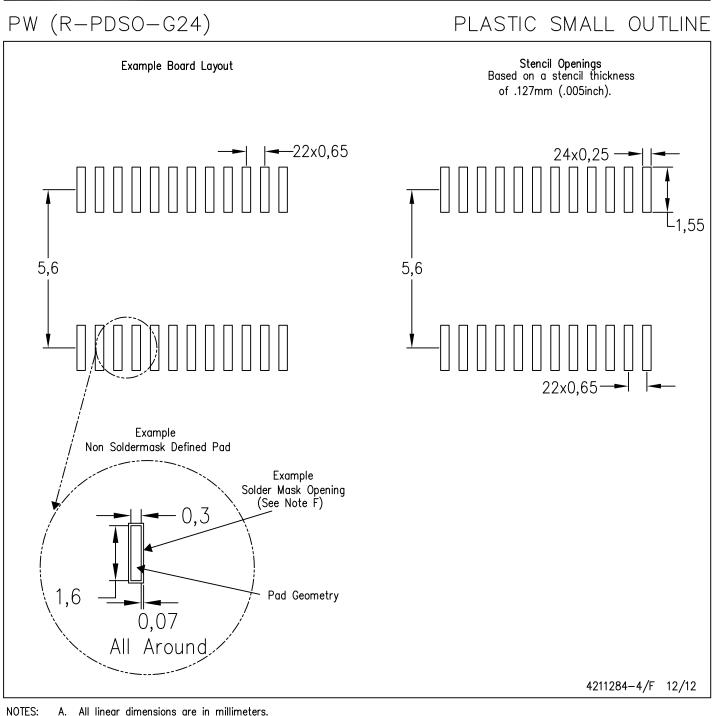
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





All linear dimensions are in millimeters. Α.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations. E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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